

# United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO		
09/890,378	01/10/2002	Frank W. Harris	UA 335	1584		
75	90 06/15/2005	EXAM	EXAMINER			
Ray L Weber			BISSETT, MELANIE D			
Renner Kenner Greive Bobak Taylor & Weber Fourth Floor First National Tower Akron, OH 44308-1456			ART UNIT	PAPER NUMBER		
			1711			
			DATE MAILED: 06/15/2003	DATE MAILED: 06/15/2005		

Please find below and/or attached an Office communication concerning this application or proceeding.

					//	1
		Application No	. A	pplicant(s)	(ċ	_
		09/890,378	H	IARRIS ET AL.		
	Office Action Summary	Examiner	A	art Unit		_
		Melanie D. Bisso		711		
Period fo	The MAILING DATE of this communication a	ppears on the cove	r sheet with the cor	respondence add	ress	
A SH THE - Exte after - If the - If NO - Faill Any	ORTENED STATUTORY PERIOD FOR REP MAILING DATE OF THIS COMMUNICATION nsions of time may be available under the provisions of 37 CFR SIX (6) MONTHS from the mailing date of this communication. e period for reply specified above is less than thirty (30) days, a reperiod for reply is specified above, the maximum statutory perioure to reply within the set or extended period for reply will, by stature to reply within the set or extended period for reply will, by stature ply received by the Office later than three months after the mailed patent term adjustment. See 37 CFR 1.704(b).	I. 1.136(a). In no event, how eply within the statutory mi d will apply and will expire ute, cause the application	ever, may a reply be timely nimum of thirty (30) days wi SIX (6) MONTHS from the to become ABANDONED (3	filed  If be considered timely, mailing date of this consistency to the constant of the cons	nmunication.	
Status	·					
1)⊠ 2a)⊠ 3)⊟	Responsive to communication(s) filed on <u>24</u> This action is <b>FINAL</b> . 2b) The Since this application is in condition for allow closed in accordance with the practice under	nis action is non-fir vance except for fo	rmal matters, prose		merits is	
Disposit	ion of Claims					
5)⊠ 6)⊠ 7)□ 8)□ Applicat	Claim(s) 1-5,9-19 and 21-25 is/are pending i 4a) Of the above claim(s) is/are withdown Claim(s) 1-5,9-19,21 and 22 is/are allowed. Claim(s) 23-25 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and ion Papers	rawn from consider				
·	The specification is objected to by the Examin					
10)	The drawing(s) filed on is/are: a) a		· ·			
	Applicant may not request that any objection to the Replacement drawing sheet(s) including the corre		·	` ,	2 1 121/4)	
11)	The oath or declaration is objected to by the	•			• •	
Priority i	under 35 U.S.C. § 119					
12)⊠ a)	Acknowledgment is made of a claim for foreign All b) Some * c) None of:  1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the priority docume application from the International Bure See the attached detailed Office action for a list	nts have been reconts have been reconts have been recontributed in the second of the second in the s	eived. eived in Application ave been received i 2(a)).	No	stage	
Attachmen		_				
	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948)	4) 📙	Interview Summary (PT Paper No(s)/Mail Date.	O-413)		
3) 🔲 Infori	mation Disclosure Statement(s) (PTO-1449 or PTO/SB/06 r No(s)/Mail Date				152)	

Application/Control Number: 09/890,378 Page 2

Art Unit: 1711

1. The rejection based on 35 USC 103 has been altered to reflect the amended subject matter. Also, a new matter rejection for the amendment has been made.

## Claim Rejections - 35 USC § 112

2. The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

3. Claims 23-25 are rejected under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement. The claim(s) contains subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention. The claims now limit the method to a step of drying the polyimide layer without further curing the polyimide. The applicants state that support for this limitation is given in the examples, which show heating the samples to temperatures of 180 °C for 48 hours but do not mention curing in this step. However, it is the examiner's position that this heating step suggests curing. Note that the temperature is close to those employed by the prior art to cure polyimide films. Also, the current specification specifically teaches heating the samples to dry and cure the films simultaneously (see p. 14 lines 5-10). It is not clear from the specification that the applicants intend to dry the films without curing.

Application/Control Number: 09/890,378 Page 3

Art Unit: 1711

## Claim Rejections - 35 USC § 103

4. The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.

## Claim Rejections - 35 USC § 103

- 5. The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.
- 6. Claims 23-25 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hougham et al. in view of Gardner et al.
- 7. From a prior Office action:

Hougham discloses low dielectric constant polyimides for use on electrical devices such as capacitors, semiconductors, and integrated circuits (abstract; col. 1 lines 26-35). One noted combination of monomers matches the applicant's formulas (I or IV) and III to form a polyimide of 6FDA-PFMB (col. 11 lines 38-58; Table 2). Such a polymer has a dry dielectric constant of 2.71 (Table 3). Because the term *about* 2.7 encompasses values slightly over 2.7 and allowing experimental error, it is the examiner's position that the cited dielectric constant meets the applicant's limitation of *less than about* 2.7.

Further, Hougham teaches dissolving polyamic acids in solvents, including DMAc and NMP, casting and drying a film, heating the film to initiate ring closure and formation of the polyimide, redissolving the film, and cycling the process until a desired molecular weight is achieved (Figure 4; col. 4 lines 13-42). Also, the formation of integrated circuits is mentioned. However, the reference does not specifically indicate casting a dissolved polyimide onto a substrate to form an integrated circuit. Gardner teaches methods for forming an integrated circuit, where the low dielectric materials are deposited or spin-coated onto the substrate (col. 5 lines 44-67).

8. Regarding the limitation that the films are dried without further curing the polyimides, it is noted that the Hougham reference teaches applying the solutions to a substrate, heating to increase the molecular weight of the polyimides, and redissolving the material. It should be noted that the "curing" in the reference refers to further increasing molecular weight by imidization reactions and chain extension and not to

Art Unit: 1711

crosslinking between polymer chain backbones. The solutions are applied to quartz substrates (col. 6), which provide an inert substrate for the intermediate material. It would have been prima facie obvious to perform the method of Hougham's invention to obtain the desired molecular weight and harvested the polyimide for shipping purposes. The reference teaches that applications for the polyimide include integrated circuits. Once the high molecular weight polyimide is redissolved for casting onto the final integrated circuit substrate, heating would not serve to further cure the material (since it would be at the desired molecular weight) but would only evaporate the casting solvent. This process would allow for the polyimide to be shipped in its final form and cast on conventional machinery at another location. The Gardner reference teaches the use of readily available materials for casting onto integrated circuits and thus supports this procedure.

#### Allowable Subject Matter

- 9. Claims 1-5, 9-19, and 21-22 are allowed.
- 10. The closest prior art, Hougham et al. (US 5,324,813 A), discloses low dielectric constant polyimides for use on electrical devices such as capacitors, semiconductors, and integrated circuits. The polyimide materials fit the applicant's formulas (I or IV) and III. However, the reference teaches a dielectric constant for this polymer of 2.71. The reference does not teach forming the polymer to have a dielectric constant of less than about 2.5 or teach the applicant's claimed thermal expansion coefficients. It is therefore the examiner's position that the applicant's claimed dielectric constant of less than

Art Unit: 1711

about 2.5 and the applicant's claimed thermal expansion coefficients provide a novel and unobvious step over the prior art integrated circuits.

## Response to Arguments

11. In response to the applicant's arguments that the presently claimed invention does not cure the polyimide but that it would destroy the primary reference to remove the curing step of the invention, it is noted that this seems contradictory to the applicant's original claims. The curing step of the primary reference serves to increase the molecular weight of the polyimide/polyamic acid coating by imidizing any remaining polyamic acid. As the process is recycled, less and less imidization occurs. As the claims stand, it is the examiner's position that the methods of claims 23-25 would be obvious over the cited prior art.

#### Conclusion

12. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, THIS ACTION IS MADE FINAL. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the

Art Unit: 1711

shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Melanie D. Bissett whose telephone number is (571) 272-1068. The examiner can normally be reached on M-F 8-4:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, James Seidleck can be reached on (571) 272-1078. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Melanie D. Bissett Patent Examiner Art Unit 1711

mdb